

## **IN THE CLAIMS:**

Please amend claims 11 and 13, and add new claims 16-19 as follows:

1-10. (Cancelled)

11. (Currently Amended) A liquid crystal display device, comprising:

thin film transistors, scanning signal lines, data signal lines which are arranged in a state that the data signal lines intersect the scanning signal lines, a pixel electrode electrically connected to an output electrode of one of the thin film transistors, and a common electrode which forms an electric field between the common electrode and the pixel electrode; and

a pixel region which is surrounded by neighboring two of the scanning signal lines and neighboring two of the data signal lines,

wherein a metal heat diffusion member which is disposed in a spaced apart manner from the thin film transistor,

the heat diffusion member has a projecting portion which is remoter than a distance between the thin film transistor and the heat diffusion member,

the projecting portion is superposed with a transparent electrode, and the transparent electrode is one of the pixel electrode and the common electrode,

the pixel electrode and the common electrode are formed in the same layer, and

an inorganic insulation film and an organic insulation film are provided between a layer on which the heat diffusion member is formed and ~~[[a]]~~ the layer ~~[[on]]~~ in which the pixel electrode and the common electrode are ~~an electrode is superpose with the heat diffusion member is formed,~~ and the organic insulation film has a removed portion at least at the superposed portion between the heat diffusion member and the transparent electrode.

12. (Cancelled)

13. (Currently Amended) A display device, comprising:

a pixel electrode and a common electrode formed in the same layer; and

a metal heat diffusion member formed in a layer different from the layer in which the pixel electrode and the common electrode are formed ~~is superposed with a transparent electrode having an insulation film therebetween,~~

wherein the heat diffusion member has a projecting portion at a portion thereof remoter than a distance between the heat diffusion member and a thin film transistor, and the heat diffusion member is superposed on the ~~transparent pixel electrode or the common~~ electrode at the projecting portion, and

wherein an inorganic insulation film and an organic insulation film are provided between a layer on which the heat diffusion member is formed and ~~[[a]] the layer [[on]] in which the pixel electrode or the common electrode are superposed with the heat diffusion member is~~ formed, and the organic insulation film has a removed portion at least at the superposed portion between the heat diffusion member and the pixel electrode or the common electrode.

14. (Withdrawn) A manufacturing method of a display device being characterized in that the method manufactures a display device which includes a metal heat diffusion member which is superposed on a lower layer of a transparent electrode by way of an insulation film, and the heat diffusion member has a projecting portion at a portion thereof remoter than a distance between the heat diffusion member and the thin film translator, wherein the heat diffusion member is superposed on the transparent electrode at the projecting portion, and the heat diffusion member and the transparent electrode are cut at the projecting portion so as to repair a short-circuit.
15. (Withdrawn) A manufacturing method of a display device according to claim 14, wherein the projecting portion and the transparent electrode are cut by heating the projecting portion with laser beams and, at the same time, the transfer of heat to the thin film transistor at the time of cutting is suppressed by the metal heat diffusion member.
16. (New) The liquid crystal display device according to claim 11, further comprising an electrode residue which short-circuits the pixel electrode and the common electrode as the pixel electrode and the common electrode are formed.
17. (New) The liquid crystal display device according to claim 16, further comprising a laser beam irradiated void on the projecting portion of the diffusion member and a simultaneously-formed laser beam irradiated void on the pixel electrode, wherein the

voids electrically insulate the pixel electrode from the common electrode after the pixel electrode and the common electrode are short-circuited.

18. (New) The display device according to claim 13, further comprising an electrode residue which short-circuits the pixel electrode and the common electrode as the pixel electrode and the common electrode are formed.
19. (New) The display device according to claim 18, further comprising a laser beam irradiated void on the projecting portion of the diffusion member and a simultaneously-formed laser beam irradiated void on the pixel electrode, wherein the voids electrically insulate the pixel electrode from the common electrode after the pixel electrode and the common electrode are short-circuited.